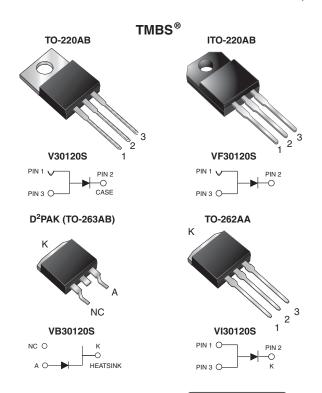
www.vishay.com

Vishay General Semiconductor

High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS

Models



PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _{RRM}	120 V					
I _{FSM}	300 A					
V _F at I _F = 30 A	0.74 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

· High efficiency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

RoHS

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30120S	VF30120S	VB30120S	VI30120S	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	120				V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	300			Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 100 mH	E _{AS}	180			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C	I _{RRM}	0.5			Α		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150			°C		

www.vishay.com

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode (1)	I _F = 5 A		V_F	0.50	-	V		
	I _F = 15 A	T _A = 25 °C		0.70	-			
	I _F = 30 A			0.99	1.10			
	I _F = 5 A			0.43	-	V		
	I _F = 15 A	T _A = 125 °C		0.60	-	İ		
	I _F = 30 A			0.74	0.82			
Reverse current per diode (2)	V _R = 90 V	T _A = 25 °C	I _R	18	-	μΑ		
		T _A = 125 °C		12	-	mA		
	V _R = 120 V	T _A = 25 °C		-	500	μΑ		
		T _A = 125 °C		22	35	mA		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30120S	VF30120S	VB30120S	VI30120S	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	1.6	4.0	1.6	1.6	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30120S-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF30120S-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30120S-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB30120S-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI30120S-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

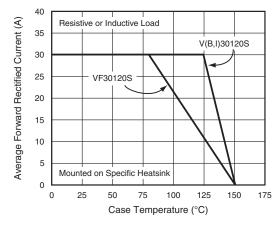


Fig. 1 - Forward Current Derating Curve

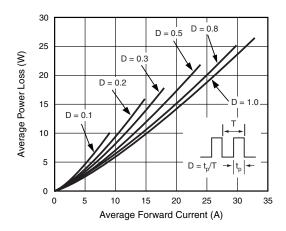


Fig. 2 - Forward Power Loss Characteristics Per Diode

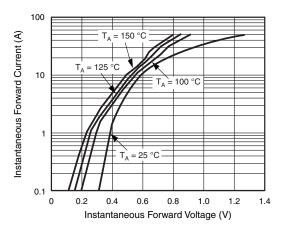


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

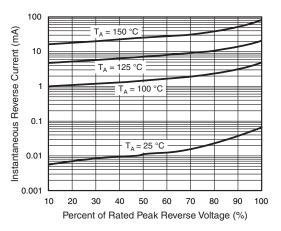


Fig. 4 - Typical Reverse Characteristics Per Diode

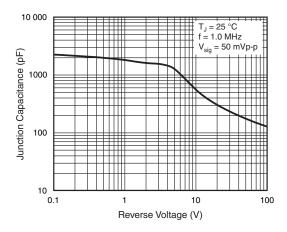


Fig. 5 - Typical Junction Capacitance Per Diode

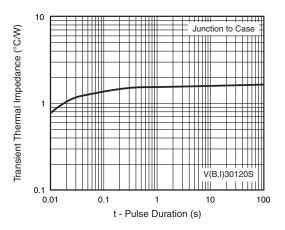


Fig. 6 - Typical Transient Thermal Impedance Per Diode

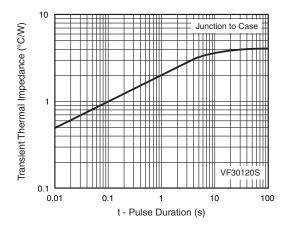
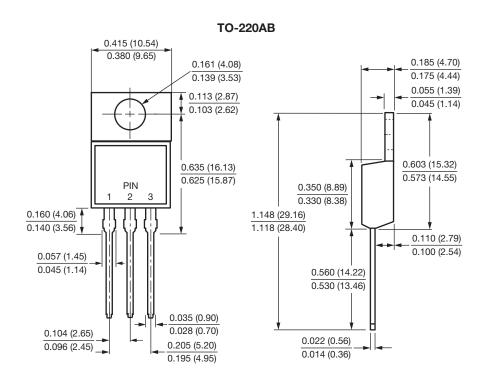


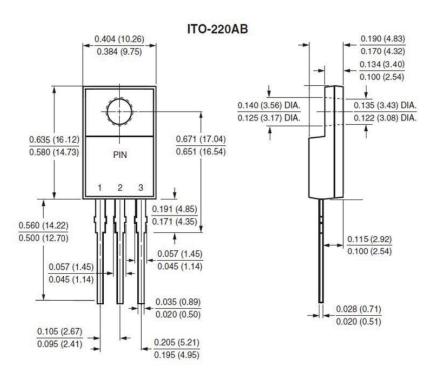
Fig. 7 - Typical Transient Thermal Impedance Per Diode

www.vishay.com

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



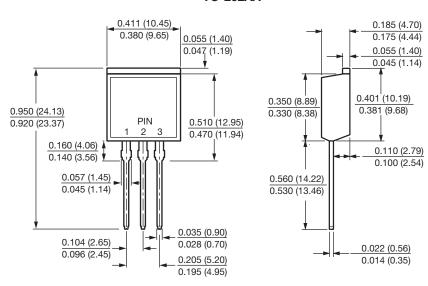


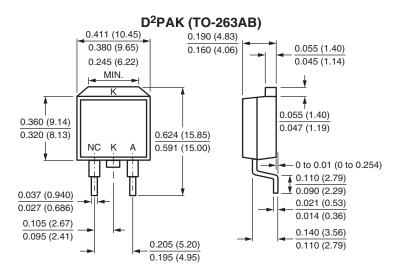
www.vishay.com

V30120S-E3, VF30120S-E3, VB30120S-E3, VI30120S-E3

Vishay General Semiconductor

TO-262AA





0.42 (10.66) MIN. 0.670 (17.02) 0.591 (15.00) 0.08 (2.032) MIN. 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRA140TRPBF MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573